

Insulated Ultrafast Rectifier Module, 230 A



SOT-227


**RoHS
COMPLIANT**

FEATURES

- Two fully independent diodes
- Fully insulated package
- Ultrafast, soft reverse recovery, with high operation junction temperature (T_J max. = 175 °C)
- Low forward voltage drop
- Optimized for power conversion: welding and industrial SMPS applications
- Easy to use and parallel
- Industry standard outline
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for industrial level

DESCRIPTION

The VS-UFL230FA60 insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The diodes structure, and its life time control, provide an ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

PRODUCT SUMMARY	
V_R	600 V
$I_{F(AV)}$ per module at $T_C = 102$ °C	230 A
t_{rr}	44 ns
Type	Modules - Diode FRED Pt®

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V_R		600	V
Continuous forward current per diode	$I_F^{(1)}$	$T_C = 85$ °C	160	A
Single pulse forward current per diode	I_{FSM}	$T_C = 25$ °C	1500	
Maximum power dissipation per module	P_D	$T_C = 85$ °C	416	W
RMS isolation voltage	V_{ISOL}	Any terminal to case, $t = 1$ minute	2500	V
Operating junction and storage temperatures	T_J, T_{Stg}		- 55 to 175	°C

Note

⁽¹⁾ Maximum continuous forward current must be limited to 100 A to do not exceed the maximum temperature of power terminals.



ELECTRICAL SPECIFICATIONS PER DIODE ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	$I_R = 100\text{ }\mu\text{A}$	600	-	-	
Forward voltage	V_{FM}	$I_F = 100\text{ A}$	-	1.28	1.44	V
		$I_F = 100\text{ A}, T_J = 125\text{ }^\circ\text{C}$	-	1.13	1.24	
		$I_F = 200\text{ A}$	-	1.48	1.66	
		$I_F = 200\text{ A}, T_J = 125\text{ }^\circ\text{C}$	-	1.37	1.55	
Reverse leakage current	I_{RM}	$V_R = V_R\text{ rated}$	-	0.1	50	μA
		$T_J = 175\text{ }^\circ\text{C}, V_R = V_R\text{ rated}$	-	0.25	2	mA
Junction capacitance	C_T	$V_R = 600\text{ V}$	-	72	-	pF

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t_{rr}	$I_F = 1.0\text{ A}, dI_F/dt = 200\text{ A}/\mu\text{s}, V_R = 30\text{ V}$	-	44	-	ns
		$T_J = 25\text{ }^\circ\text{C}$	-	104	-	
		$T_J = 125\text{ }^\circ\text{C}$	-	210	-	
Peak recovery current	I_{RRM}	$T_J = 25\text{ }^\circ\text{C}$	-	10	-	A
		$T_J = 125\text{ }^\circ\text{C}$	-	22	-	
Reverse recovery charge	Q_{rr}	$T_J = 25\text{ }^\circ\text{C}$	-	520	-	nC
		$T_J = 125\text{ }^\circ\text{C}$	-	2200	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction to case, single leg conducting	R_{thJC}		-	-	0.43	$^\circ\text{C}/\text{W}$
Junction to case, both leg conducting			-	-	0.215	
Case to heatsink	R_{thCS}	Flat, greased surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque			-	1.3	-	Nm
Case style			SOT-227			

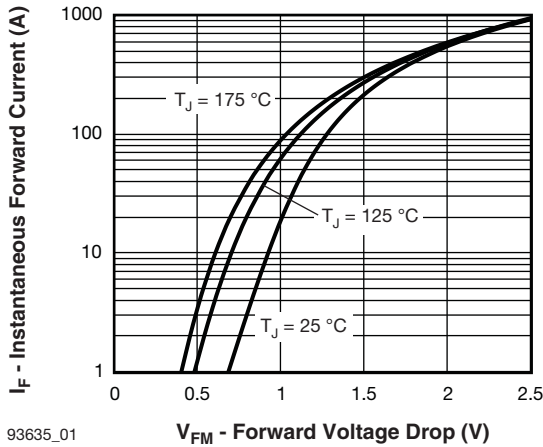


Fig. 1 - Typical Forward Voltage Drop Characteristics

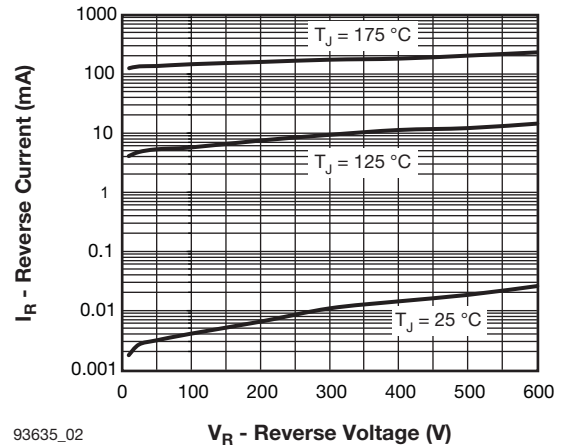


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

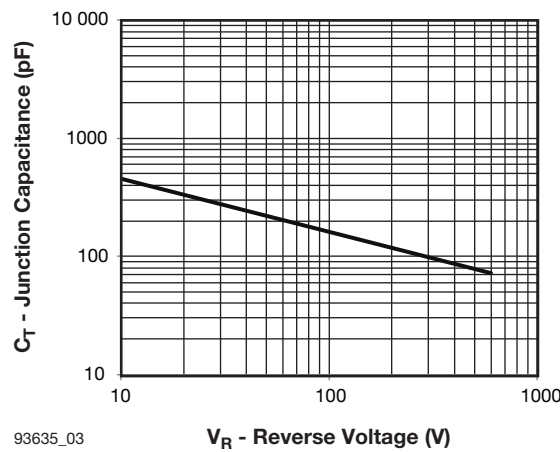


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

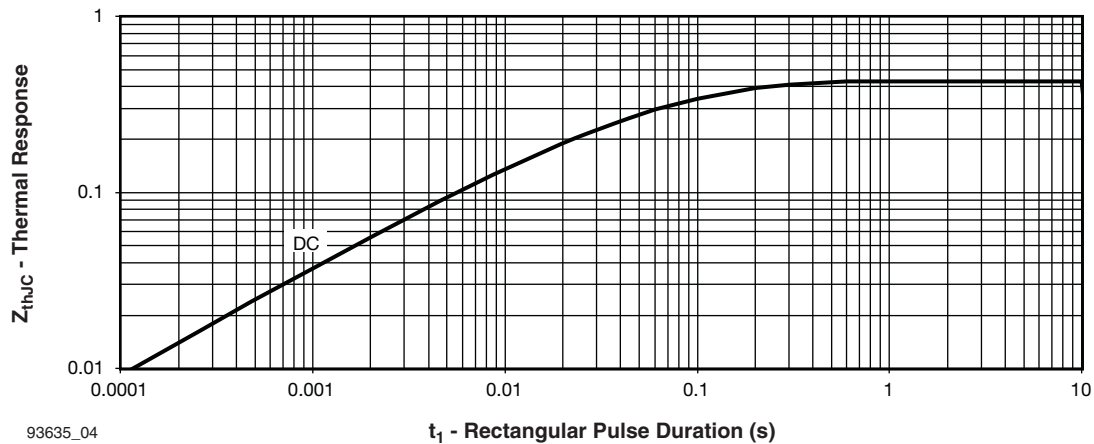
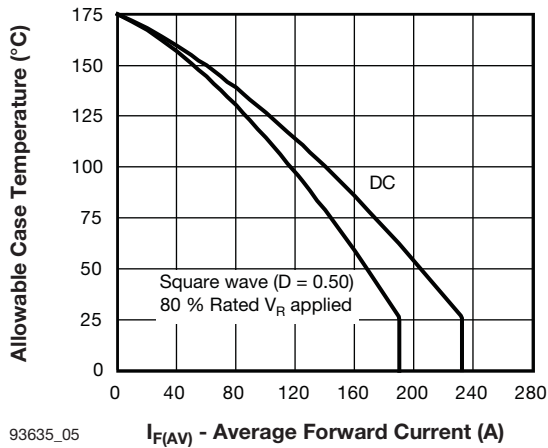
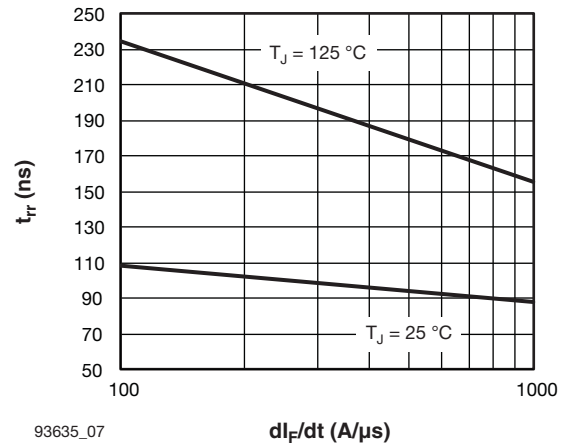


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



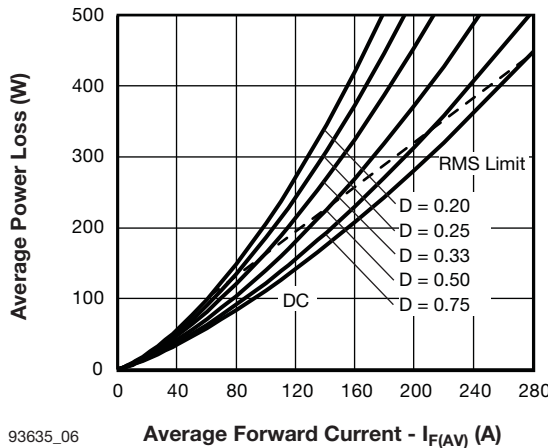
93635_05 $I_{F(AV)}$ - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



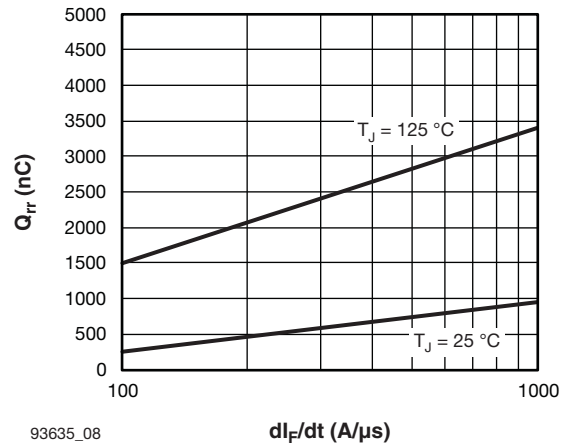
93635_07 dI_F/dt (A/μs)

Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt



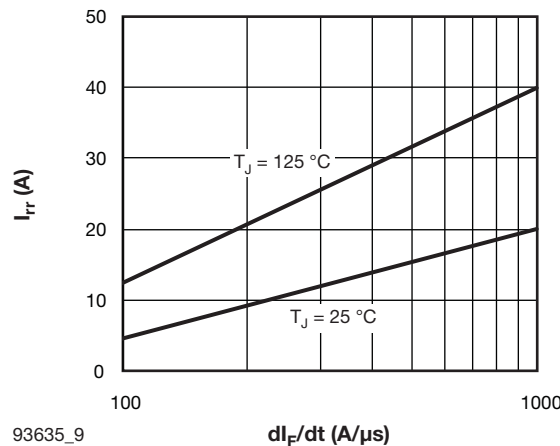
93635_06 Average Forward Current - $I_{F(AV)}$ (A)

Fig. 6 - Forward Power Loss Characteristics



93635_08 dI_F/dt (A/μs)

Fig. 8 - Typical Stored Charge vs. dI_F/dt



93635_9

dI_F/dt (A/μs)

Fig. 9 - Typical I_{rr} Diode vs. dI_F/dt

Note

- (1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
- Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- Pd_{REV} = Inverse power loss = $V_{R1} \times I_{rr}$ (1 - D); I_{rr} at V_{R1} = Rated V_R

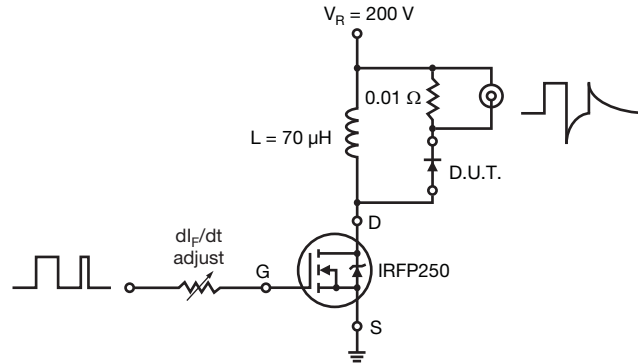
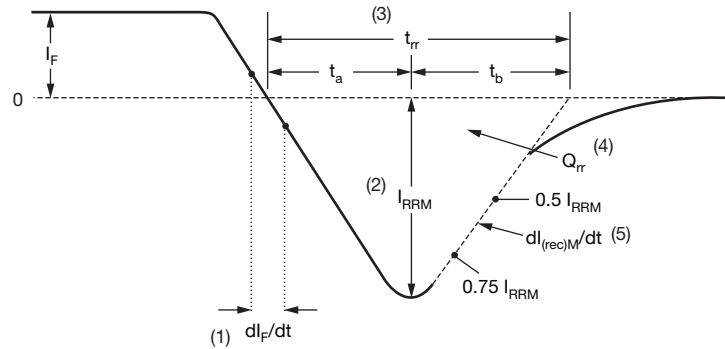


Fig. 10 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt - rate of change of current through zero crossing
- (2) I_{RRM} - peak reverse recovery current
- (3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.50 I_{RRM}$ extrapolated to zero current.
- (4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}
- (5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

Fig. 11 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code	VS-	UF	L	230	F	A	60
	①	②	③	④	⑤	⑥	⑦

- 1** - Vishay Semiconductors product
- 2** - Ultrafast rectifier
- 3** - Ultrafast Pt diffused, low V_F
- 4** - Current rating (230 = 230 A)
- 5** - Circuit configuration (2 separate diodes, parallel pin-out)
- 6** - Package indicator (SOT-227 standard isolated base)
- 7** - Voltage rating (60 = 600 V)

CIRCUIT CONFIGURATION		
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
2 separate diodes, parallel pin-out	F	<p>Lead Assignment</p>

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95423
Packaging information	www.vishay.com/doc?95425



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